

Description

The AU0861P0 is a bi-directional TVS diode, utilizing leading monolithic silicon technology to provide fast response time, very low capacitance and low ESD clamping voltage, making this device an ideal solution for protecting voltage sensitive data and power line. The AU0861P0 complies with the IEC 61000-4-2 (ESD) with ±15kV air and ±8kV contact discharge. It is assembled into an ultrasmall lead-free package. The small size and very low capacitance make AU0861P0 an ideal choice to protect cell phone, digital cameras, audio players, data interface and many other portable applications.

Features

- Ultra small package: 0.6x0.3x0.3mm
- Protects one data or power line
- Very low capacitance: 3pF typical
- Ultra low leakage: nA level
- Operating voltage: 8V
- Low clamping voltage
- 2-pin leadless package
- Complies with following standards:
 - IEC 61000-4-2 (ESD) immunity test
 Air discharge: ±15kV
 Contact discharge: ±8kV
 - –EC61000-4-5 (Lightning) 3A (8/20µs)
- RoHS compliant

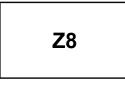
Mechanical Characteristics

- Package: DFN0603-2 (0.6x0.3x0.3mm)
- Case Material: "Green" Molding Compound.
- Terminal Connections: See Diagram Below
- Marking Information: See Below

Applications

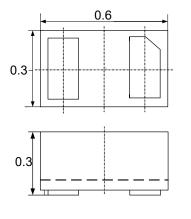
- Cellular Handsets and Accessories
- Personal Digital Assistants
- Notebooks and Handhelds
- Portable Instrumentation
- Digital Cameras
- Peripherals
- Audio Players
- Keypads, Side Keys, USB 2.0, LCD Displays

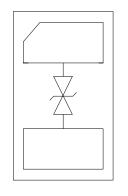
Marking Information



Ordering Information

Dimensions and Pin Configuration





Package Dimensions

Circuit and Pin Schematic

Part Number	Number Packaging Reel Siz	
AU0861P0	8000/Tape & Reel	7 inch



Absolute Maximum Ratings (T_A=25°C unless otherwise specified)

Parameter	Symbol	Value	Unit	
ESD per IEC 61000-4-2 (Air)		±15	kV	
ESD per IEC 61000-4-2 (Contact)	VESD	±8		
Operating Temperature Range	TJ	−55 to +125	°C	
Storage Temperature Range	Tstg	−55 to +150	°C	

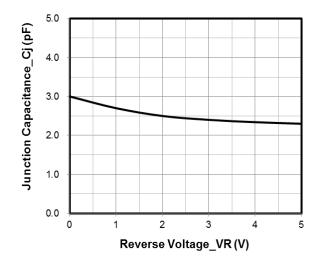
Electrical Characteristics (T_A=25°C unless otherwise specified)

Parameter	Symbol	Min	Тур	Мах	Unit	Test Condition
Reverse Working Voltage	VRWM			8	V	Pin 1 to Pin 2 or Pin 2 to Pin 1
Breakdown Voltage	Vbr	8.5			V	IT = 1mA, Pin 1 to Pin 2 or Pin 1 to Pin 2
Reverse Leakage Current	I _R			0.2	μA	VRWM = 8V, Pin 1 to Pin 2 or Pin 1 to
Clamping Voltage	Vc			15	V	IPP = 3A (8 x 20µs pulse), Pin 1 to
Junction Capacitance	CJ		3		pF	VR = 0V, f = 1MHz

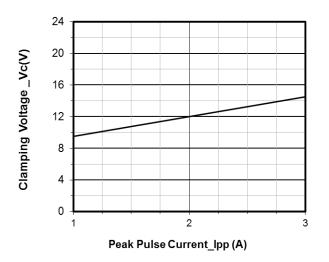


AU0861P0

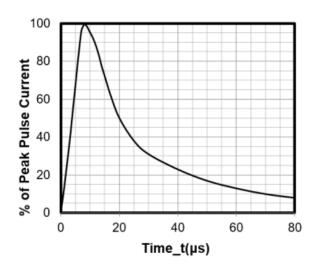
Typical Performance Characteristics (T_A=25°C unless otherwise Specified)



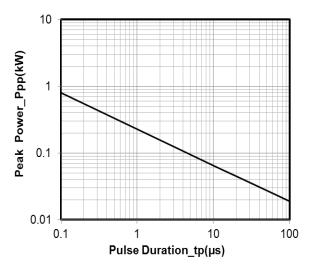
Junction Capacitance vs. Reverse Voltage



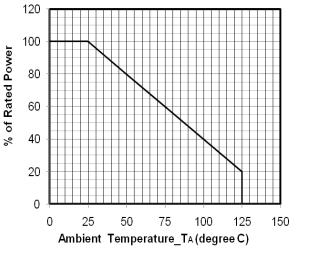
Clamping Voltage vs. Peak Pulse Current (tp = 8/20us)



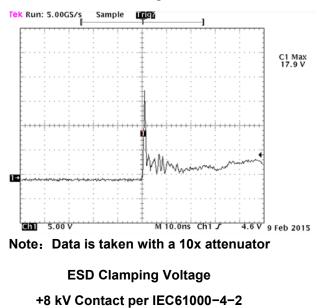




Peak Pulse Power vs. Pulse Time

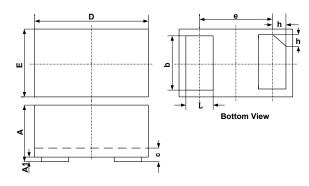


Power Derating Curve



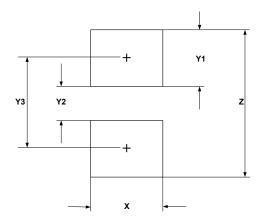


DFN0603-2 Package Outline Drawing



	DIMENSIONS			
-	MILLIMETERS			
SYM	MIN	NOM	MAX	
А	0.230			0.330
A1	0.000	0.020		0.050
b	0.215	0.245		0.275
с	0.120	0.150		0.180
D	0.550	0.600		0.650
е	0.355 BSC			
E	0.250	0.300		0.350
L	0.160	0.190		0.220
h	0.079 BSC			

Suggested Land Pattern



SYM	DIMENSIONS			
STIVI	MILLIMETERS	INCHES		
х	0.30	0.012		
Y1	0.25	0.010		
Y2	0.15	0.006		
Y3	0.40	0.016		
Z	0.65	0.026		

Contact Information

Applied Power Microelectronics Inc. Website: http://www.appliedpowermicro.com Email: sales@appliedpowermicro.com

Phone: +86 (0519) 8399 3606

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